

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC393AP, TC74HC393AF, TC74HC393AFN

DUAL BINARY COUNTER

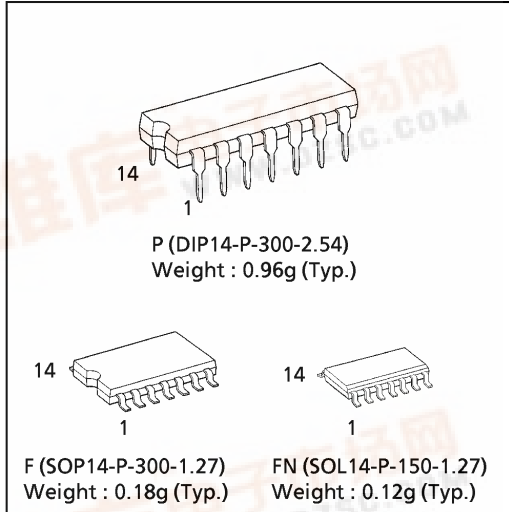
The TC74HC393A is a high speed CMOS 4 - BIT BINARY COUNTER fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. It contains two independent counter circuits in one package, so that counting or frequency division of eight binary bits can be achieved with one IC.

This device changes state on the negative going transition of the \overline{CK} pulse. The counter can be reset to "0" (QA~QD="L") by a high at the CLR input regardless of other inputs. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

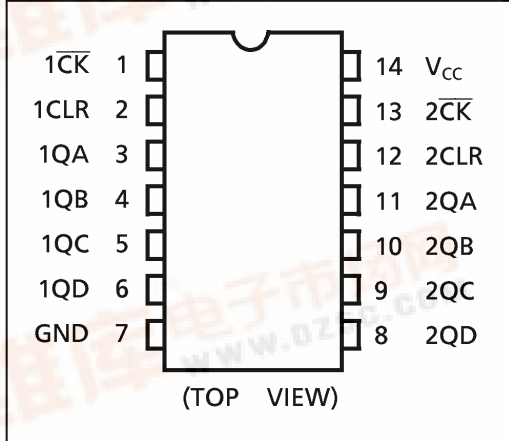
FEATURES :

- High Speed..... $f_{MAX} = 72\text{MHz}(\text{typ.})$ at $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{Min.})$
- Output Drive Capability 10 LSTTL Loads
- Symmetrical Output Impedance: $|I_{OH}| = |I_{OL}| = 4\text{mA}(\text{Min.})$
- Balanced Propagation Delays... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range.. $V_{CC} (\text{opr.}) = 2\text{V} \sim 6\text{V}$
- Pin and Function Compatible with 74LS393

(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT

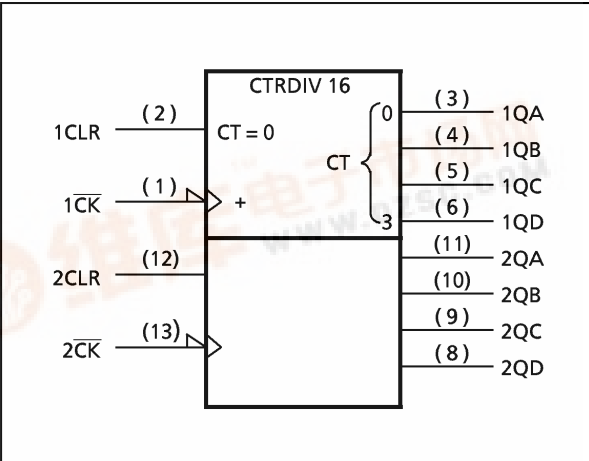


TRUTH TABLE

INPUTS		OUTPUTS			
\overline{CK}	CLR	QA	QB	QC	QD
X	H	L	L	L	L
\downarrow	L	COUNT UP			
\uparrow	L	NO CHANGE			

X : Don't Care

IEC LOGIC SYMBOL

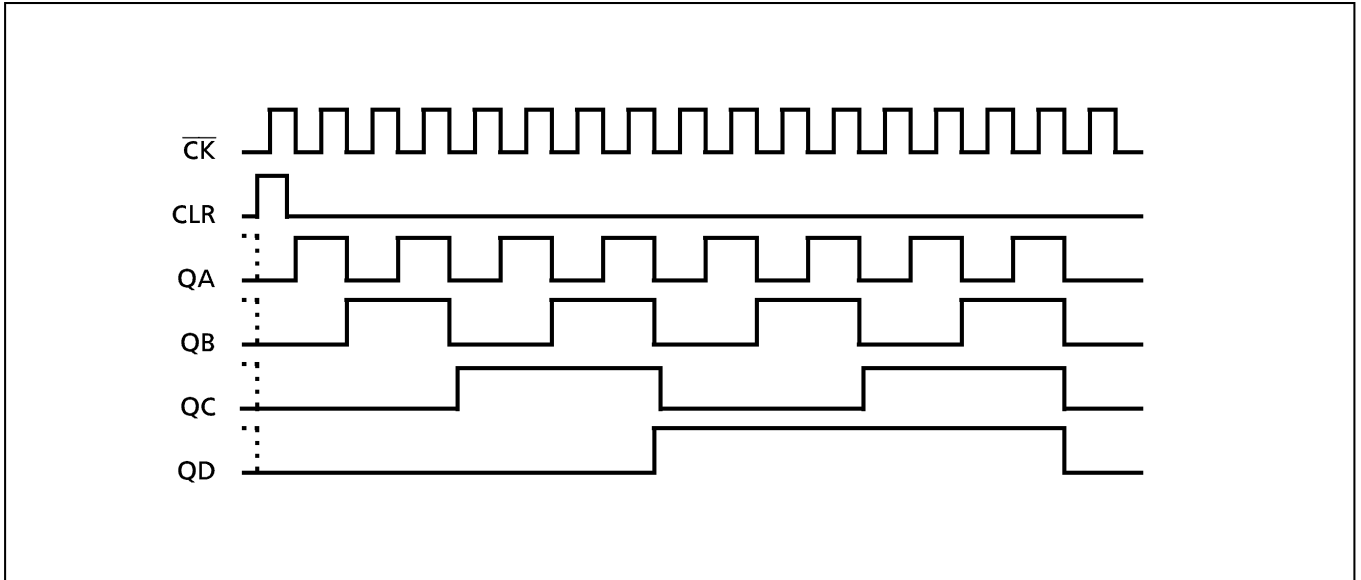


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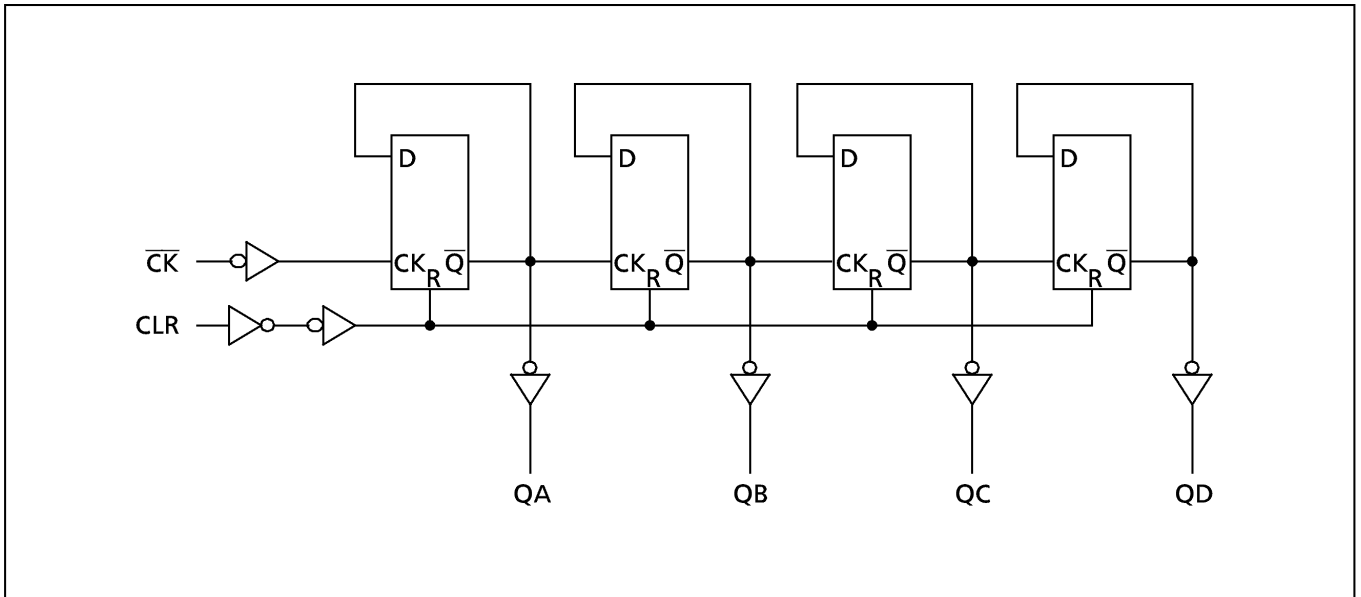
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TIMING CHART



SYSTEM DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7	V
DC Input Voltage	V_{IN}	-0.5~ $V_{CC}+0.5$	V
DC Output Voltage	V_{OUT}	-0.5~ $V_{CC}+0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	-65~150	°C

*500mW in the range of $T_a = -40^\circ\text{C} \sim 65^\circ\text{C}$. From $T_a = 65^\circ\text{C}$ to 85°C a derating factor of $-10\text{mW}/^\circ\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 ($V_{CC} = 2.0\text{V}$) 0~500 ($V_{CC} = 4.5\text{V}$) 0~400 ($V_{CC} = 6.0\text{V}$)	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \sim 85^\circ\text{C}$		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High - Level Input Voltage	V_{IH}		2.0	1.50	—	—	1.50	—	V	
			4.5	3.15	—	—	3.15	—		
			6.0	4.20	—	—	4.20	—		
Low - Level Input Voltage	V_{IL}		2.0	—	—	0.50	—	0.50	V	
			4.5	—	—	1.35	—	1.35		
			6.0	—	—	1.80	—	1.80		
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\mu\text{A}$	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			6.0	5.9	6.0	—	5.9	—		
			$I_{OH} = -4\text{ mA}$ $I_{OH} = -5.2\text{ mA}$	4.5	4.18	4.31	—	4.13	—	
				6.0	5.68	5.80	—	5.63	—	
			Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\mu\text{A}$	2.0	—	0.0	
4.5	—	0.0					0.1	—	0.1	
6.0	—	0.0				0.1	—	0.1		
$I_{OL} = 4\text{ mA}$ $I_{OL} = 5.2\text{ mA}$	4.5	—				0.17	0.26	—	0.33	
	6.0	—				0.18	0.26	—	0.33	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC}$ or GND				6.0	—	—	± 0.1	—
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	6.0	—	—	4.0	—	40.0		

TIMING REQUIREMENTS (Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C		Ta = -40~85°C	UNIT
				TYP.	LIMIT	LIMIT	
Minimum Pulse Width (\overline{CK})	$t_{W(H)}$ $t_{W(L)}$		2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Pulse Width (CLR)	$t_{W(H)}$		2.0	—	75	95	
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Removal Time	t_{rem}		2.0	—	25	30	
			4.5	—	5	6	
			6.0	—	5	5	
Clock Frequency	f		2.0	—	6	5	MHz
			4.5	—	32	27	
			6.0	—	38	32	

AC ELECTRICAL CHARACTERISTICS ($C_L = 15\text{pF}$, $V_{CC} = 5\text{V}$, Ta = 25°C, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		—	4	8	ns
Propagation Delay Time ($\overline{CK} - QA$)	t_{pLH} t_{pHL}		—	12	20	
Propagation Delay Time ($\overline{CK} - QB$)	t_{pLH} t_{pHL}		—	16	31	
Propagation Delay Time ($\overline{CK} - QC$)	t_{pLH} t_{pHL}		—	21	38	
Propagation Delay Time ($\overline{CK} - QD$)	t_{pLH} t_{pHL}		—	25	46	
Propagation Delay Time (CLR - Qn)	t_{pHL}		—	15	26	
Maximum Clock Frequency	f_{MAX}		35	72	—	MHz

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, Input t_r = t_f = 6ns)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t _{TLH} t _{THL}		2.0	—	25	75	—	95	ns
			4.5	—	7	15	—	19	
			6.0	—	6	13	—	16	
Propagation Delay Time (CK-QA)	t _{pLH} t _{pHL}		2.0	—	45	120	—	150	
			4.5	—	15	24	—	30	
			6.0	—	13	20	—	26	
Propagation Delay Time (CK-QB)	t _{pLH} t _{pHL}		2.0	—	60	180	—	225	
			4.5	—	20	36	—	45	
			6.0	—	17	31	—	38	
Propagation Delay Time (CK-QC)	t _{pLH} t _{pHL}		2.0	—	80	220	—	275	
			4.5	—	25	44	—	55	
			6.0	—	21	37	—	47	
Propagation Delay Time (CK-QD)	t _{pLH} t _{pHL}		2.0	—	100	260	—	325	
			4.5	—	30	52	—	65	
			6.0	—	26	44	—	55	
Propagation Delay Time (CLR-Qn)	t _{pHL}		2.0	—	55	150	—	190	
			4.5	—	18	30	—	38	
			6.0	—	15	26	—	33	
Maximum Clock Frequency	f _{MAX}		2.0	6	22	—	5	—	MHZ
			4.5	32	67	—	27	—	
			6.0	38	77	—	32	—	
Input Capacitance	C _{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C _{PD} (1)			—	40	—	—	—	

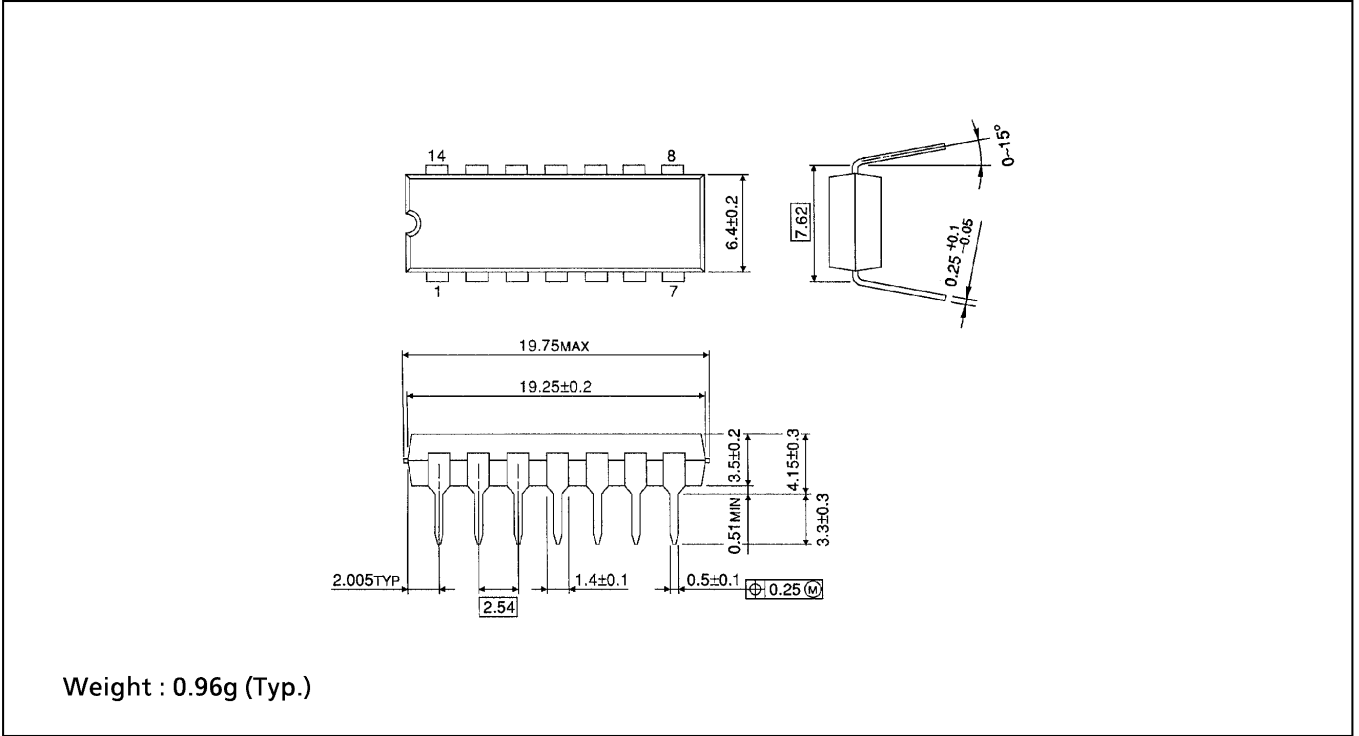
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2 \text{ (per counter)}$$

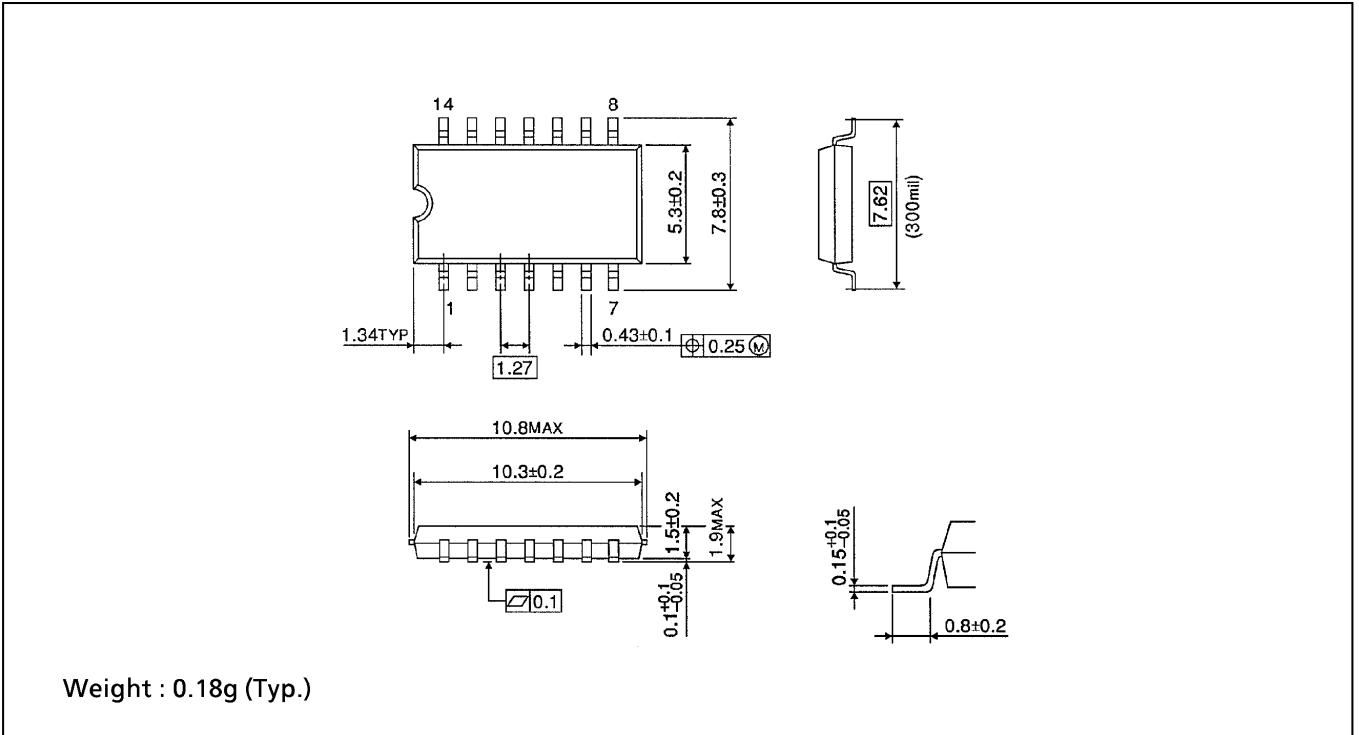
DIP 14PIN OUTLINE DRAWING (DIP14-P-300-2.54)

Unit in mm



SOP 14PIN (200mil BODY) OUTLINE DRAWING (SOP14-P-300-1.27)

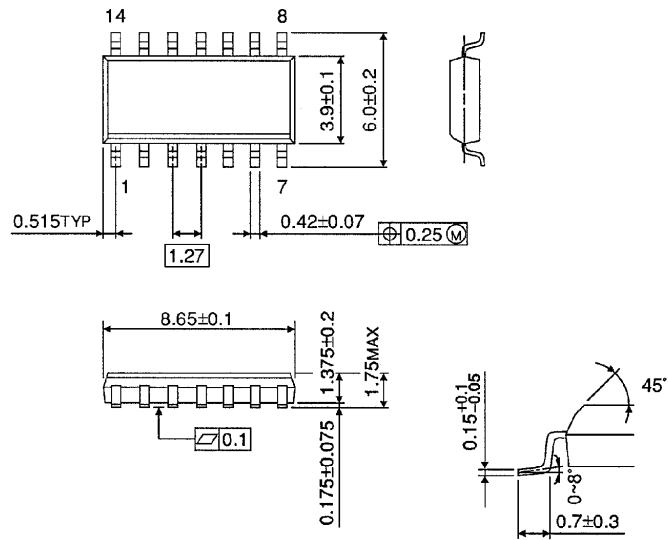
Unit in mm



SOP 14PIN (150mil BODY) OUTLINE DRAWING (SOL14-P-150 -1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.12g (Typ.)